

Technical Data
Data Sheet N1676 Rev. -

403DMQ080/100 SCHOTTKY RECTIFIER

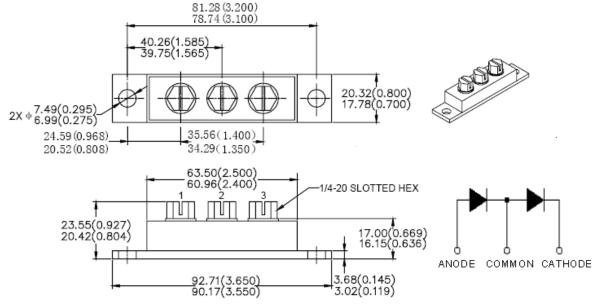
Applications:

- High current switching power supply Plating power supply Free-Wheeling diodes
- Reverse battery protection Converters UPS System Welding

Features:

- 175 °C T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Product contain Pb
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm/Inches



Please Note: Suffix "R" Denotes For Reversed Polarity

PRM4 (Isolated)

MARKING, MOLDING RESIN

Marking for 403DMQ080/100, 1st row SS YYWWL, 2nd row 403DMQ080/100 Where YY is the manufacture year

WW is the manufacture week code

L is the wafer's Lot Number

Molding resin

Epoxy resin UL:94V-0

[•] Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 🗏 (86) 25-87123907 •

[•] FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •





Technical Data Data Sheet N1676 Rev. -**Maximum Ratings:**

Characteristics	Symbol	Condition		Max.	Units
Peak Inverse Voltage	V_{RWM}	-	80	403DMQ080	V
			100	403DMQ100	
Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =85°C,	200	per leg	Α
		rectangular wave form	400	per device	
Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	3960		A
Non-Repetitive Avalanche Energy(peg leg)	E _{AS}	$T_J=25^{\circ}C$, $I_{AS}=1A,L=30mH$	15		mJ
Repetitive Avalanche Current(peg leg)	I _{AR}	Current decaying linearly to zero in 1 µsec Frequency limited by T _J max. V _A =1.5×V _R typical	1		A

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop (per leg) *	V_{F1}	@ 200A, Pulse, T _J = 25 °C @ 400A, Pulse, T _J = 25 °C	0.83 0.97	V
	V_{F2}	@ 200A, Pulse, T_J = 125 °C@ 400A, Pulse, T_J = 125 °C	0.69 0.82	V
Reverse Current (per leg) *	I _{R1}	$@V_R = \text{rated } V_R T_J = 25 ^{\circ}\text{C}$	6	mA
	I _{R2}	$@V_R = \text{rated } V_R T_J = 125 ^{\circ}\text{C}$	140	mA
Junction Capacitance (per leg)	C _T	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	5500	pF
Typical Series Inductance (per leg)	L _s	Measured lead to lead 5 mm from package body	5.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

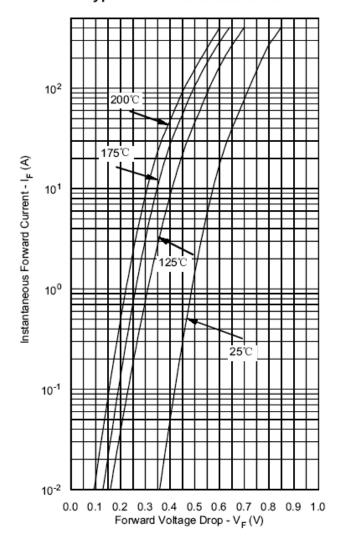
Characteristics	Symbol	Condition	Specifi	Units		
Junction Temperature	T_J	-	-55 to	°C		
Storage Temperature	T _{stg}	-	-55 to	°C		
Maximum Thermal Resistance Junction to Case (per leg)	$R_{ ext{ heta}JC}$	DC operation	0.40		°C/W	
Maximum Thermal Resistance Junction to Case (per package)	$R_{ heta JC}$	DC operation	0.20		°C/W	
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.10		°C/W	
Mounting Torque	Тм	-	Mounting Torque Terminal Torque	24(min) 35(max) 35(min) 46(max)	Kg-cm	
Approximate Weight	wt	-	79	g		
Case Style	PRM4 Isolated					

Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 ■ (86) 25-87123907 •
 FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •

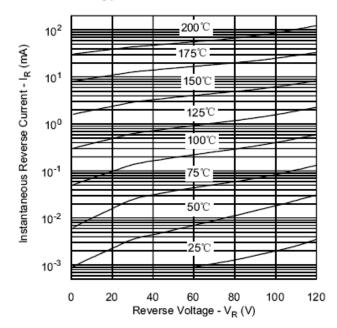


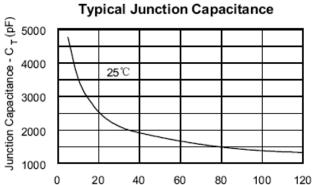
Technical Data
Data Sheet N1676 Rev. -

Typical Forward Characteristics



Typical Reverse Characteristics





Reverse Voltage - V_R (V)

[•] Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 🗏 (86) 25-87123907 •

[•] FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •



403DMQ SERIES

Technical Data
Data Sheet N1676 Rev. -

DISCLAIMER:

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).
- 2- in cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
- 3- In no event shall SMC Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
- .
 4- In no event shall SMC Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Sangdest Microelectronics (Nanjing) Co., Ltd.
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Sangdest Microelectronics (Nanjing) Co., Ltd.
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..

[•] FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •